

isc N-Channel MOSFET Transistor

IPD50R399CP,IIPD50R399CP

FEATURES

- Static drain-source on-resistance:
 R_{DS}(on)≤399mΩ
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

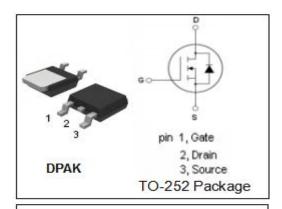
· Fast switching

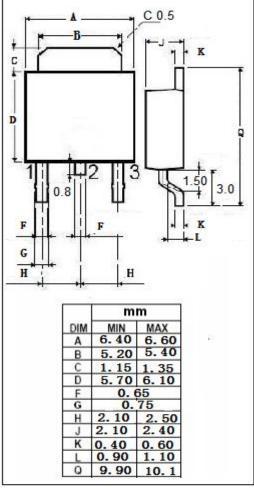
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|---|---------------|--------------|--|
| V _{DSS} | Drain-Source Voltage | 500 | V | |
| V _{GS} | Gate-Source Voltage | ±20 | V | |
| ID | Drain Current-Continuous | 9 | А | |
| I _{DM} | Drain Current-Single Pulsed | gle Pulsed 20 | | |
| P _D | Total Dissipation @T _C =25°C | 83 | W | |
| Tj | Max. Operating Junction Temperature | 150 | $^{\circ}$ C | |
| T _{stg} | Storage Temperature | -55~150 | $^{\circ}$ | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|----------|---------------------------------------|-----|------|
| Rth(j-c) | Channel-to-case thermal resistance | 1.5 | °C/W |
| Rth(j-a) | Channel-to-ambient thermal resistance | 62 | °C/W |







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------|--------------------------------|--|-----|-----|-----|------------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D =250 μ A | 500 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | VDS=VGS; I _D =330 μ A | 2.5 | | 3.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =4.9A | | | 399 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} =20V | | | 0.1 | μ A |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =500V; V _{GS} = 0V | | | 1 | μ А |
| V _{SD} | Diode forward voltage | I _F =4.9A, V _{GS} = 0V | | | 1.2 | V |

NOTICE:

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